

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

N-Channel Junction Silicon FET

EC3A04B — Low-Frequency General-Purpose Amplifier, **Impedance Converter Applications**

Applicatins

· Low-frequency general-purpose amplifier, impedance conversion, infrared sensor applications.

Features

- · Small IGSS.
- · Small Ciss.
- · Ultraminiature package facilitates miniaturization in end products.
- · Halogen free compliance (UL94HB).

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSX		30	V
Gate-to-Drain Voltage	V _{GDS}		-30	V
Gate Current	IG		10	mA
Drain Current	ID		10	mA
Allowable Power Dissipation	PD		100	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Symbol Conditions	Ratings			Unit
	Symbol		min	typ	max	Offic
Gate-to-Drain Breakdown Voltage	V(BR)GDS	IG=-10μA, VDS=0V	-30			V
Gate-to-Source Leakage Current	IGSS	V _{GS} =-20V, V _{DS} =0V			-1.0	nA
Cutoff Voltage	VGS(off)	Vng=10V, In=1µA	-0.18	-0.65	-2.2	V

Marking: KC Continued on next page.

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SANYO Semiconductor Co., Ltd.

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EC3A04B

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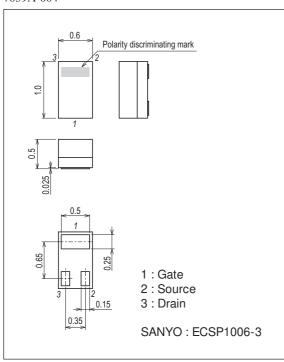
Parameter	Symbol Conditions	Conditions	Ratings			Unit
		min	typ	max	Office	
Drain Current	IDSS	V _{DS} =10V, V _{GS} =0V	0.6*		3.0*	mA
Forward Transfer Admittance	yfs	V _{DS} =10V, V _{GS} =0V, f=1kHz	3.0	5.0		mS
Input Capacitance	Ciss	V _{DS} =10V, V _{GS} =0V, f=1MHz		4		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, V _{GS} =0V, f=1MHz		1.1		pF
Static Drain-to-Source On-State Resistance	R _{DS} (on)	V _{DS} =10mV, V _{GS} =0V		200		Ω

 $\mbox{\ensuremath{^{\star}}}$: The EC3A04B is classified by IDSS as follows : (unit : mA).

Rank	2	3
IDSS	0.6 to 1.5	1.2 to 3.0

Package Dimensions

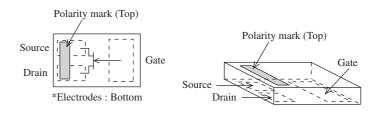
unit : mm (typ) 7039A-004

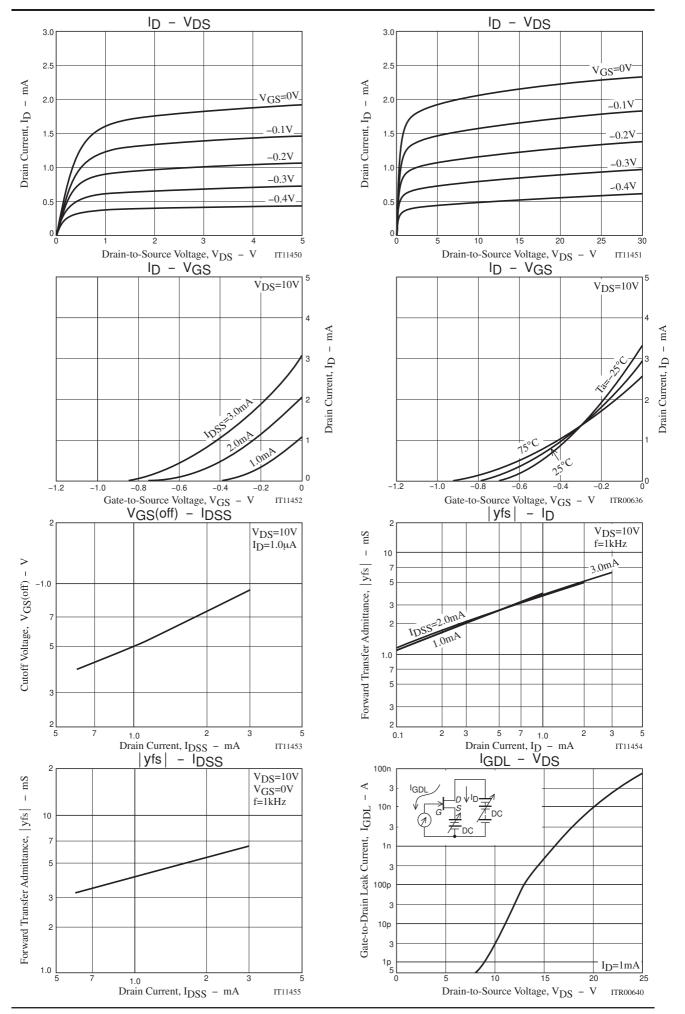


Type No. Indication (Top view)

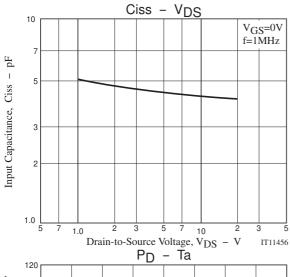
КС

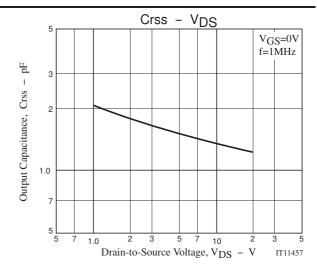
Electrical Connection (Top view)

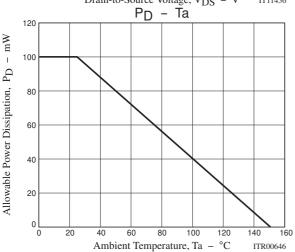




EC3A04B







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